

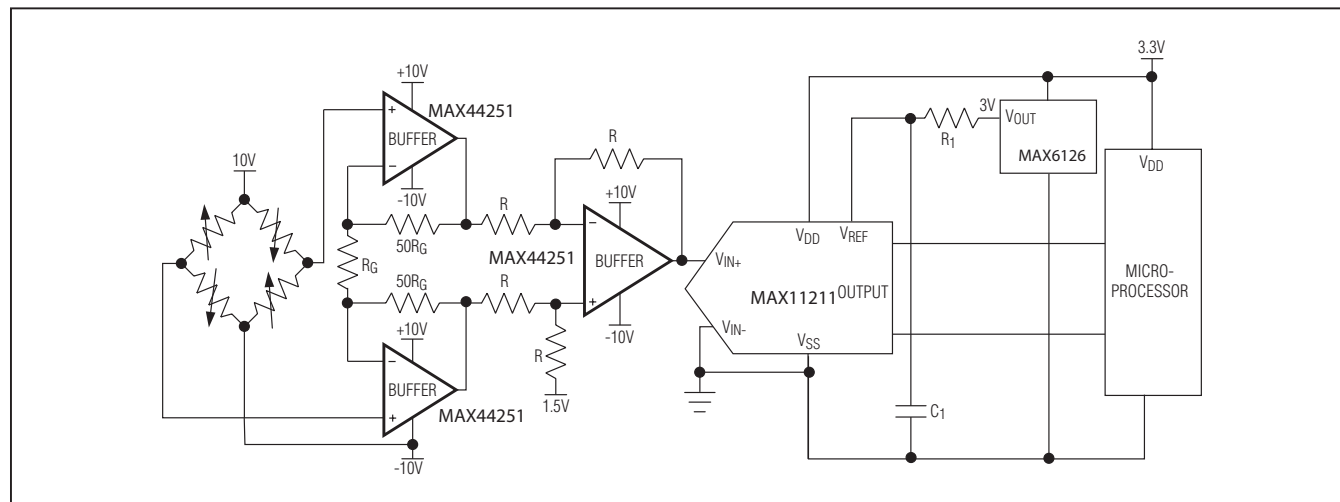
20V, Ultra-Precision, Low-Noise Op Amps

Ordering Information appears at end of data sheet.

- High Accuracy Enables Precision Signal Chain Acquisition
 - $6\mu\text{V}$ Input Offset Voltage (max) at Room Temperature
 - TCV_{OS} of $19\text{nV}/^\circ\text{C}$ (max)
 - Low $5.9\text{nV}/\sqrt{\text{Hz}}$ Input-Referred Voltage Noise
 - $123\text{nV}_{\text{P-P}}$ in 0.1Hz to 10Hz
 - 10MHz Gain-Bandwidth Product
 - Rail-to-Rail Output
 - Fast 400ns Settling Time
- 2.7V to 20V Power-Supply Range Supports Wide Range of Sensors
- Integrated EMI Filter Reduces Impact of Radio Frequency Interference on Signal Chain Performance

- Strain Gauges
- Pressure Transducers
- Medical Instrumentation
- Precision Instrumentation
- Load Cell and Bridge Transducer Amplification

Functional Diagrams appear at end of data sheet.



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MAX44250/MAX44251/ MAX44252

20V, Ultra-Precision, Low-Noise Op Amps

Absolute Maximum Ratings

Supply Voltage (V_{DD} to V_{SS}).....-0.3V to +22V
 All Other Pins.....($V_{SS} - 0.3V$) to ($V_{DD} + 0.3V$)
 Short-Circuit Duration to Either Supply Rail 1s
 Continuous Input Current (any pin)..... $\pm 20mA$
 Differential Input Voltage..... $\pm 6V$
 Maximum Power Dissipation ($T_A = +70^\circ C$)
 5-Pin SOT23 (derate 3.1mW/ $^\circ C$ above $+70^\circ C$).....246.7mW
 8-Pin SOT23 (derate 9.1mW/ $^\circ C$ above $+70^\circ C$).....727mW

μMAX (derate 4.5 mW/ $^\circ C$ above $+70^\circ C$)362mW
 SO (derate 8.3 mW/ $^\circ C$ above $+70^\circ C$)666.7mW
 Operating Temperature Range..... $-40^\circ C$ to $+125^\circ C$
 Junction Temperature $+150^\circ C$
 Storage Temperature Range..... $-65^\circ C$ to $+150^\circ C$
 Lead Temperature (soldering, 10s) $+300^\circ C$
 Soldering Temperature (reflow) $+260^\circ C$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Thermal Characteristics (Note 1)

5-Pin SOT23

Junction-to-Ambient Thermal Resistance (θ_{JA}) 324.3 $^\circ C/W$
 Junction-to-Case Thermal Resistance (θ_{JC})82 $^\circ C/W$

8-Pin SOT23

Junction-to-Ambient Thermal Resistance (θ_{JA}) 196 $^\circ C/W$
 Junction-to-Case Thermal Resistance (θ_{JC})70 $^\circ C/W$

μMAX

Junction-to-Ambient Thermal Resistance (θ_{JA})221 $^\circ C/W$
 Junction-to-Case Thermal Resistance (θ_{JC})42 $^\circ C/W$

SO

Junction-to-Ambient Thermal Resistance (θ_{JA})120 $^\circ C/W$
 Junction-to-Case Thermal Resistance (θ_{JC})37 $^\circ C/W$

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Electrical Characteristics

($V_{DD} = 10V$, $V_{SS} = 0V$, $V_{IN+} = V_{IN-} = V_{DD}/2$, $R_L = 10k\Omega$ to $V_{DD}/2$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
POWER SUPPLY							
Supply Voltage Range	V _{DD}	Guaranteed by PSRR		2.7		20	V
Power-Supply Rejection Ratio (Note 3)	PSRR	V _{DD} = 2.7V to 20V, V _{CM} = 0V		140	145		dB
Quiescent Current per Amplifier (MAX44250)	I _{DD}	R _L = ∞	T _A = +25°C		1.22	1.7	mA
			-40°C < T _A < +125°C			1.85	
Quiescent Current per Amplifier (MAX44251/MAX44252)	I _{DD}	R _L = ∞	T _A = +25°C		1.15	1.55	mA
			-40°C < T _A < +125°C			1.75	
Power-Up Time	t _{ON}				25		μs
DC SPECIFICATIONS							
Input Common-Mode Range	V _{CM}	Guaranteed by CMRR test		V _{SS} - 0.05		V _{DD} - 1.5	V
Common-Mode Rejection Ratio (Note 3)	CMRR	T _A = +25°C, V _{CM} = -0.05V to (V _{DD} - 1.5V)		133	140		dB
		-40°C < T _A < +125°C		130			
Input Offset Voltage (MAX44250) (Note 3)	V _{OS}	T _A = +25°C			3	9	μV

Electrical Characteristics (continued)

($V_{DD} = 10V$, $V_{SS} = 0V$, $V_{IN+} = V_{IN-} = V_{DD}/2$, $R_L = 10k\Omega$ to $V_{DD}/2$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Input Offset Voltage (MAX44251/ MAX44252)(Note 3)	V _{OS}	T _A = +25°C		3		6	μV
		-40°C < T _A < +125°C		7			
Input Offset Voltage Drift (MAX44250) (Note 3)	TC V _{OS}			5		26	nV/°C
Input Offset Voltage Drift (MAX44251/MAX44252)(Note 3)	TC V _{OS}			5		19	nV/°C
Input Bias Current (MAX44250) (Note 3)	I _B	T _A = +25°C		200		1400	pA
Input Bias Current (MAX44251/ MAX44252)(Note 3)	I _B	T _A = +25°C		200		1300	pA
		-40°C < T _A < +125°C		2400			
Input Offset Current (Note 3)	I _{OS}			400			pA
Open-Loop Gain (Note 3)	A _{VOL}	250mV ≤ V _{OUT} ≤ V _{DD} - 250mV, R _L = 10kΩ to V _{DD} /2	T _A = +25°C	145	154		dB
			-40°C < T _A < +125°C	136			
Output Short-Circuit Current		To V _{DD} or V _{SS}	Noncontinuous	96			mA
Output Voltage Low (MAX44250)	V _{OL}	V _{OUT} - V _{SS}	R _L = 10kΩ to V _{DD} /2	12	26		mV
			R _L = 2kΩ to V _{DD} /2	45	92		
Output Voltage Low (MAX44251/MAX44252)	V _{OL}	V _{OUT} - V _{SS}	R _L = 10kΩ to V _{DD} /2	12	25		mV
			R _L = 2kΩ to V _{DD} /2	45	85		
Output Voltage High (MAX44250)	V _{OH}	V _{DD} - V _{OUT}	R _L = 10kΩ to V _{DD} /2	18	40		mV
			R _L = 2kΩ to V _{DD} /2	71	148		
Output Voltage High (MAX44251/MAX44252)	V _{OH}	V _{DD} - V _{OUT}	R _L = 10kΩ to V _{DD} /2	18	37		mV
			R _L = 2kΩ to V _{DD} /2	71	135		
AC SPECIFICATIONS							
Input Voltage-Noise Density	e _N	f = 1kHz		5.9			nV/√Hz
Input Voltage Noise		0.1Hz < f < 10Hz		123			nV _{P-P}
Input Current-Noise Density	i _N	f = 1kHz		0.6			pA/√Hz
Input Capacitance	C _{IN}			2			pF
Gain-Bandwidth Product	GBW			10			MHz
Phase Margin	PM	C _L = 20pF		60			Degrees
Slew Rate	SR	A _V = 1V/V, V _{OUT} = 2V _{P-P}		8			V/μs
Capacitive Loading	C _L	No sustained oscillation, A _V = 1V/V		500			pF
Total Harmonic Distortion	THD	V _{OUT} = 2V _{P-P} , A _V = +1V/V, R _L = 10kΩ to V _{DD} /2	f = 1kHz	-124			dB
			f = 20kHz	-119			
Settling Time		To 0.01%, V _{OUT} = 2V step, A _V = -1V/V		400			ns

MAX44250/MAX44251/ MAX44252

20V, Ultra-Precision, Low-Noise Op Amps

Electrical Characteristics

($V_{DD} = 3.3V$, $V_{SS} = 0V$, $V_{IN+} = V_{IN-} = V_{DD}/2$, $R_L = 10k\Omega$ to $V_{DD}/2$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
POWER SUPPLY							
Quiescent Current Per Amplifier (MAX44250)	I _{DD}	R _L = ∞	T _A = +25°C	1.17	1.65	mA	
			-40°C < T _A < +125°C	1.80			
Quiescent Current Per Amplifier (MAX44251/MAX44252))	I _{DD}	R _L = ∞	T _A = +25°C	1.1	1.5	mA	
			-40°C < T _A < +125°C	1.65			
Power-Up Time	t _{ON}			25		μs	
DC SPECIFICATIONS							
Input Common-Mode Range	V _{CM}	Guaranteed by CMRR test		V _{SS} - 0.05	V _{DD} - 1.5	V	
Common-Mode Rejection Ratio (Note 3)	CMRR	T _A = +25°C, V _{CM} = -0.05V to (V _{DD} - 1.5V)		120	129	dB	
		-40°C < T _A < +125°C		117			
Input Offset Voltage (MAX44250)(Note 3)	V _{OS}			3	8.5	μV	
Input Offset Voltage (MAX44251/ MAX44252)(Note 3)	V _{OS}	T _A = +25°C		3	5.5	μV	
		-40°C < T _A < +125°C		6.5			
Input Offset Voltage Drift (MAX44250)(Note 3)	TC V _{OS}			8	25	nV/°C	
Input Offset Voltage Drift (MAX44251/MAX44252)(Note 3)	TC V _{OS}			8	18	nV/°C	
Input Bias Current (MAX44250)(Note 3)	I _B			200	1450	pA	
Input Bias Current (MAX44251/ MAX44252)(Note 3)	I _B	T _A = +25°C		200	1100	pA	
		-40°C < T _A < +125°C		1200			
Input Offset Current (Note 3)	I _{OS}			400		pA	
Open-Loop Gain (Note 3)	A _{VOL}	250mV ≤ V _{OUT} ≤ V _{DD} - 250mV, R _L = 10kΩ to V _{DD} /2	T _A = +25°C	136	151	dB	
			-40°C < T _A < +125°C	133			
Output Short-Circuit Current		To V _{DD} or V _{SS}	Noncontinuous	58		mA	
Output Voltage Low (MAX44250)	V _{OL}	V _{OUT} - V _{SS}	R _L = 10kΩ to V _{DD} /2	5	26	mV	
			R _L = 2kΩ to V _{DD} /2	17	46		
Output Voltage Low (MAX44251/MAX44252)	V _{OL}	V _{OUT} - V _{SS}	R _L = 10kΩ to V _{DD} /2	5	22	mV	
			R _L = 2kΩ to V _{DD} /2	17	42		
Output Voltage High	V _{OH}	V _{DD} - V _{OUT}	R _L = 10kΩ to V _{DD} /2	9	22	mV	
			R _L = 2kΩ to V _{DD} /2	29	52		

Electrical Characteristics (continued)

($V_{DD} = 3.3V$, $V_{SS} = 0V$, $V_{IN+} = V_{IN-} = V_{DD}/2$, $R_L = 10k\Omega$ to $V_{DD}/2$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$.) (Note 2)

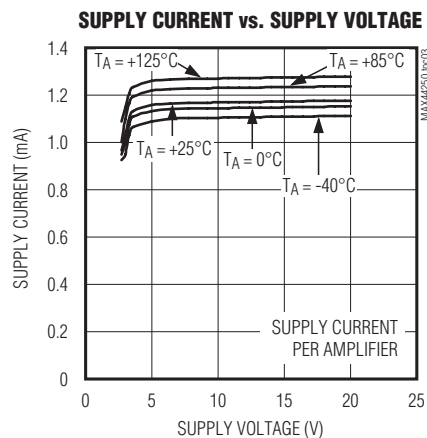
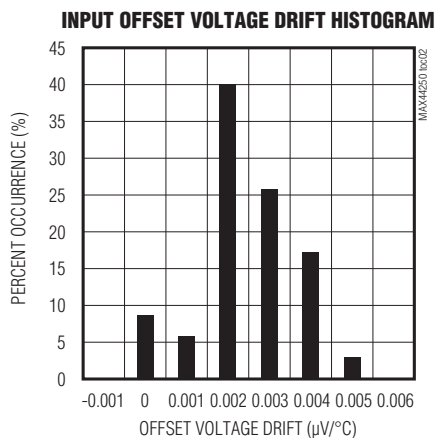
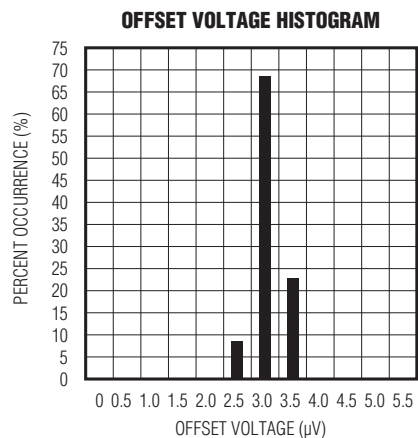
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
AC SPECIFICATIONS						
Input Voltage-Noise Density	e_N	$f = 1kHz$		6.2		$nV/\sqrt{Hz}$
Input Voltage Noise		$0.1Hz < f < 10Hz$		123		nV_{P-P}
Input Current-Noise Density	i_N	$f = 1kHz$		0.3		$pA/\sqrt{Hz}$
Input Capacitance	C_{IN}			2		pF
Gain-Bandwidth Product	GBW			10		MHz
Phase Margin	PM	$C_L = 20pF$		60		Degrees
Slew Rate	SR	$A_V = 1V/V$, $V_{OUT} = 1V_{P-P}$, 10% to 90%		5		$V/\mu s$
Capacitive Loading	C_L	No sustained oscillation, $A_V = 1V/V$		500		pF
Total Harmonic Distortion	THD	$V_{OUT} = 1V_{P-P}$, $A_V = +1V/V$, $V_{CM} = V_{DD}/4$, $R_L = 10k\Omega$ to $V_{DD}/2$	$f = 1kHz$	-124		dB
			$f = 20kHz$	-100		
Settling Time		To 0.01%, $V_{OUT} = 1V$ step, $A_V = -1V/V$		200		ns

Note 2: All devices are 100% production tested at $T_A = +25^\circ C$. Temperature limits are guaranteed by design.

Note 3: Guaranteed by design.

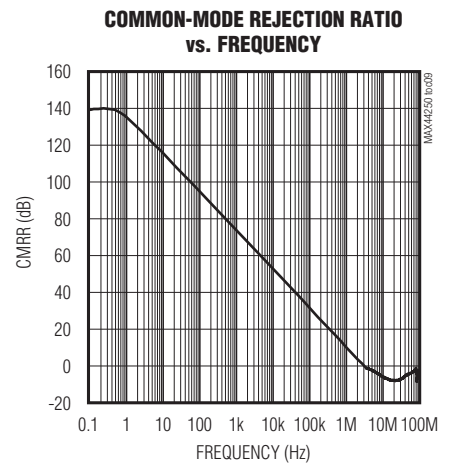
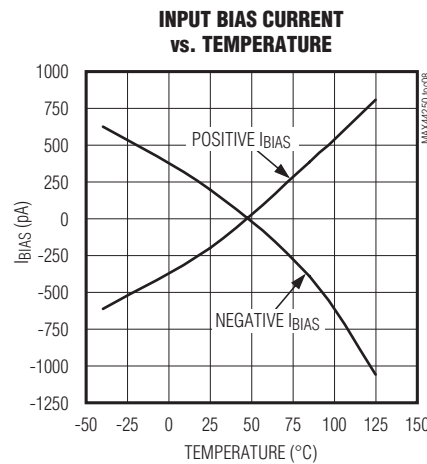
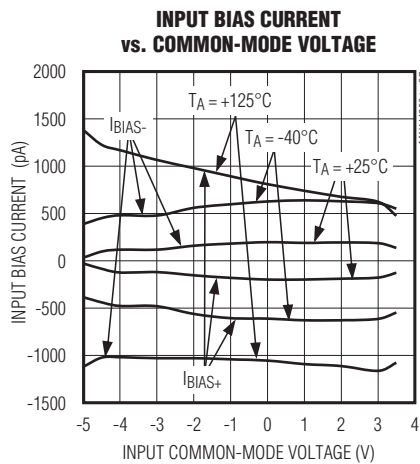
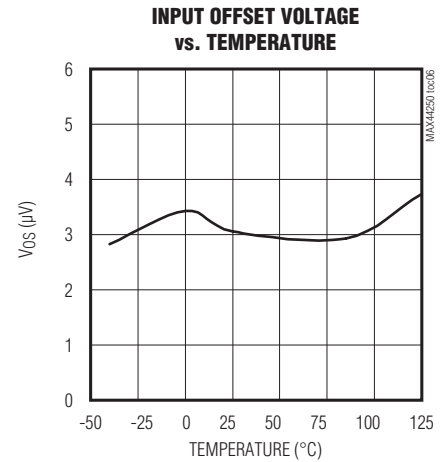
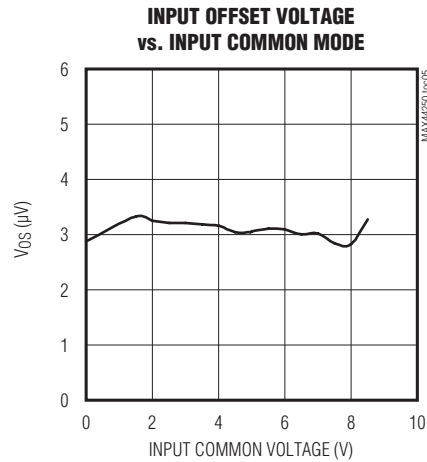
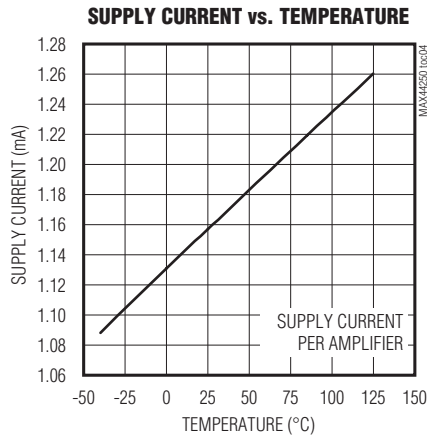
Typical Operating Characteristics

($V_{DD} = 10V$, $V_{SS} = 0V$, outputs have $R_L = 10k\Omega$ to $V_{DD}/2$. $T_A = +25^\circ C$, unless otherwise specified.)



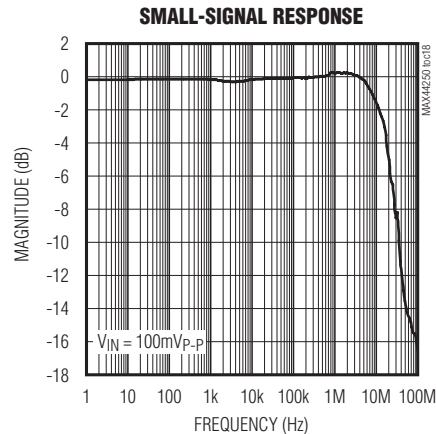
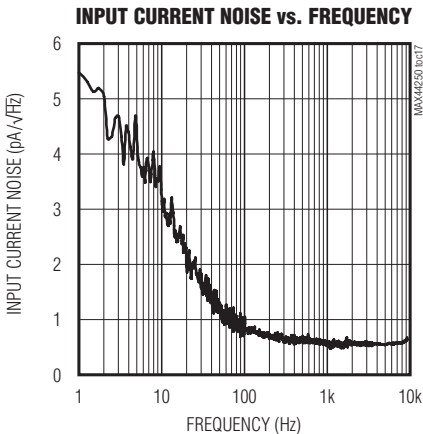
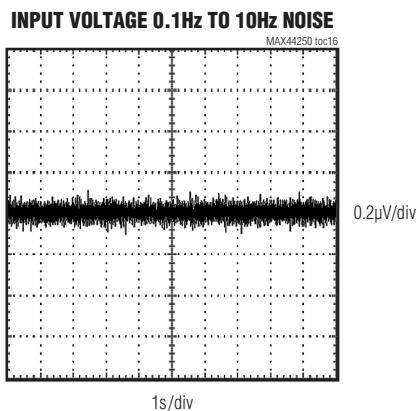
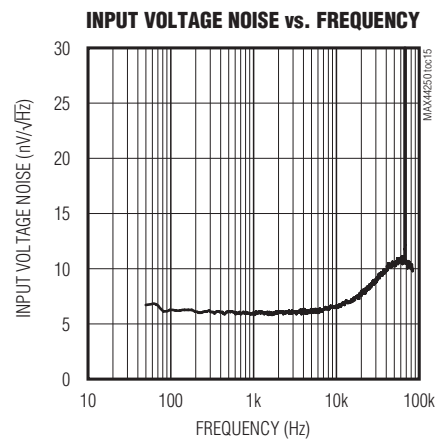
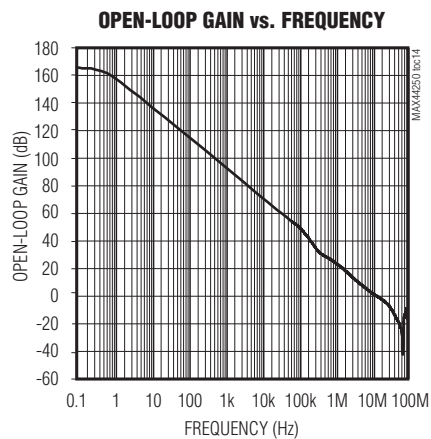
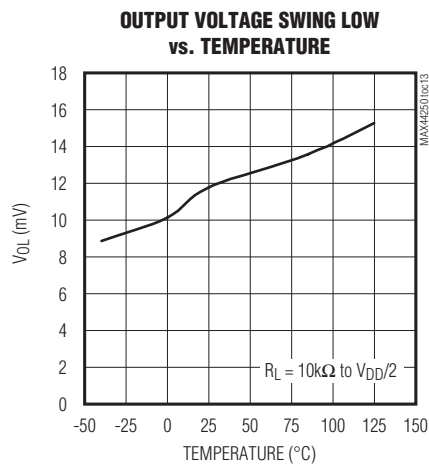
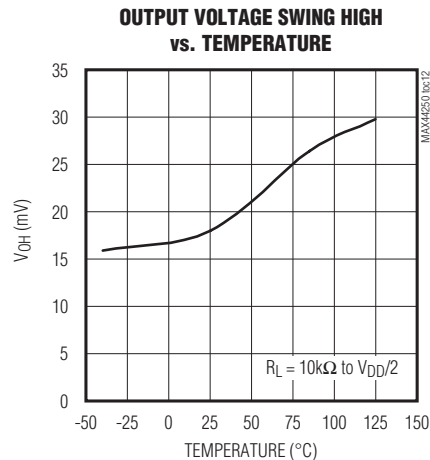
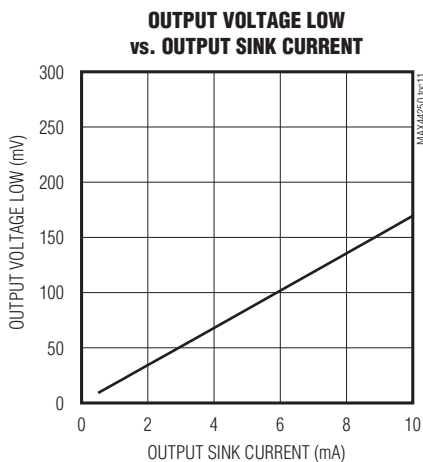
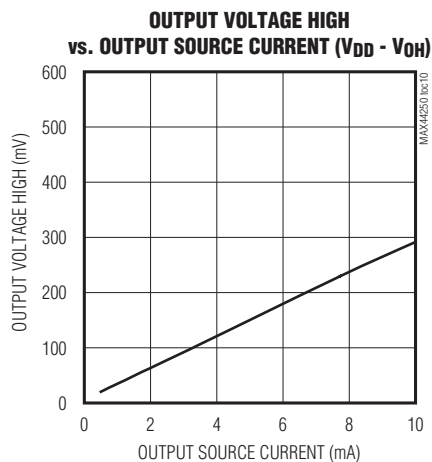
Typical Operating Characteristics (continued)

($V_{DD} = 10V$, $V_{SS} = 0V$, outputs have $R_L = 10k\Omega$ to $V_{DD}/2$. $T_A = +25^\circ C$, unless otherwise specified.)



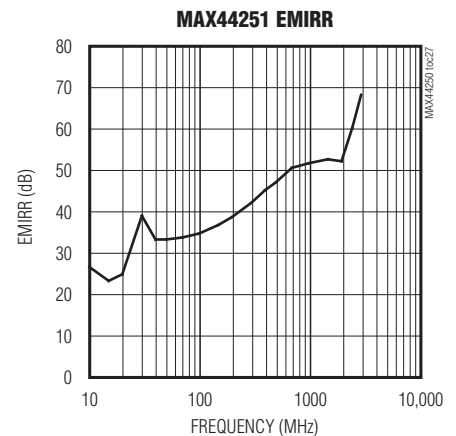
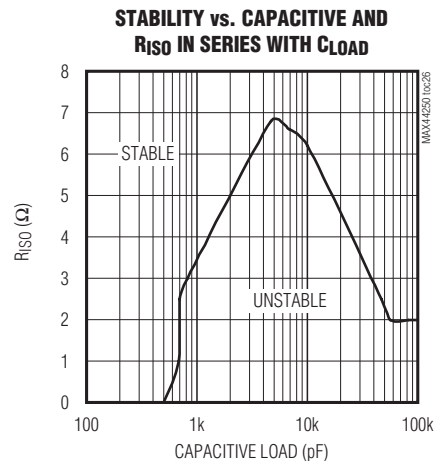
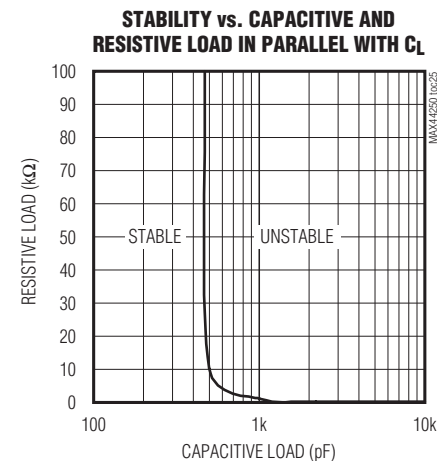
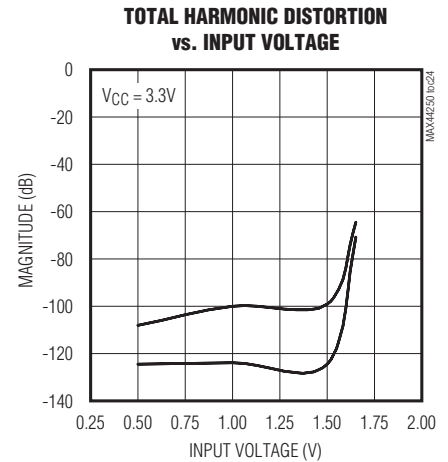
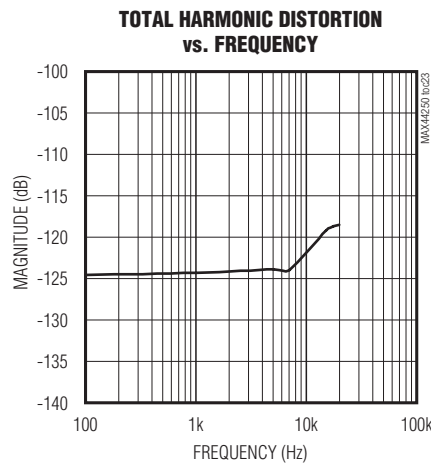
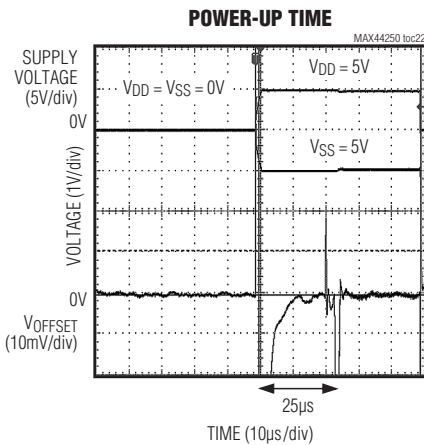
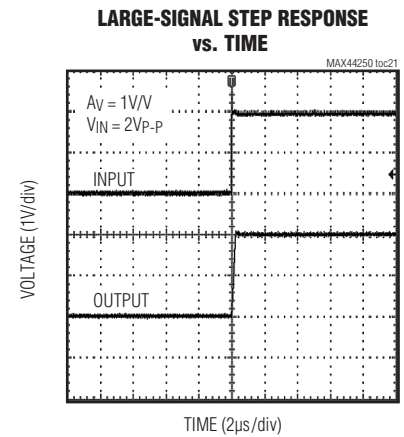
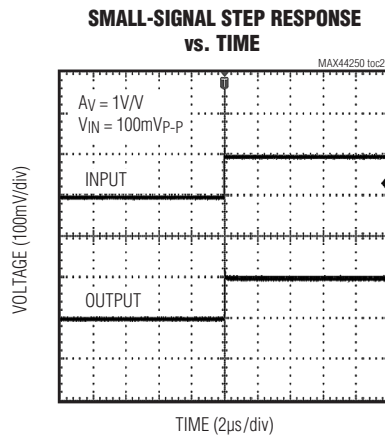
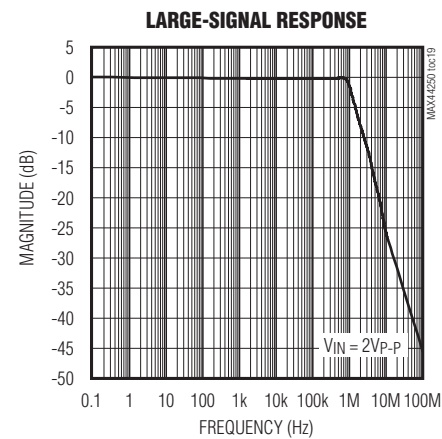
Typical Operating Characteristics (continued)

($V_{DD} = 10V$, $V_{SS} = 0V$, outputs have $R_L = 10k\Omega$ to $V_{DD}/2$. $T_A = +25^\circ C$, unless otherwise specified.)



Typical Operating Characteristics (continued)

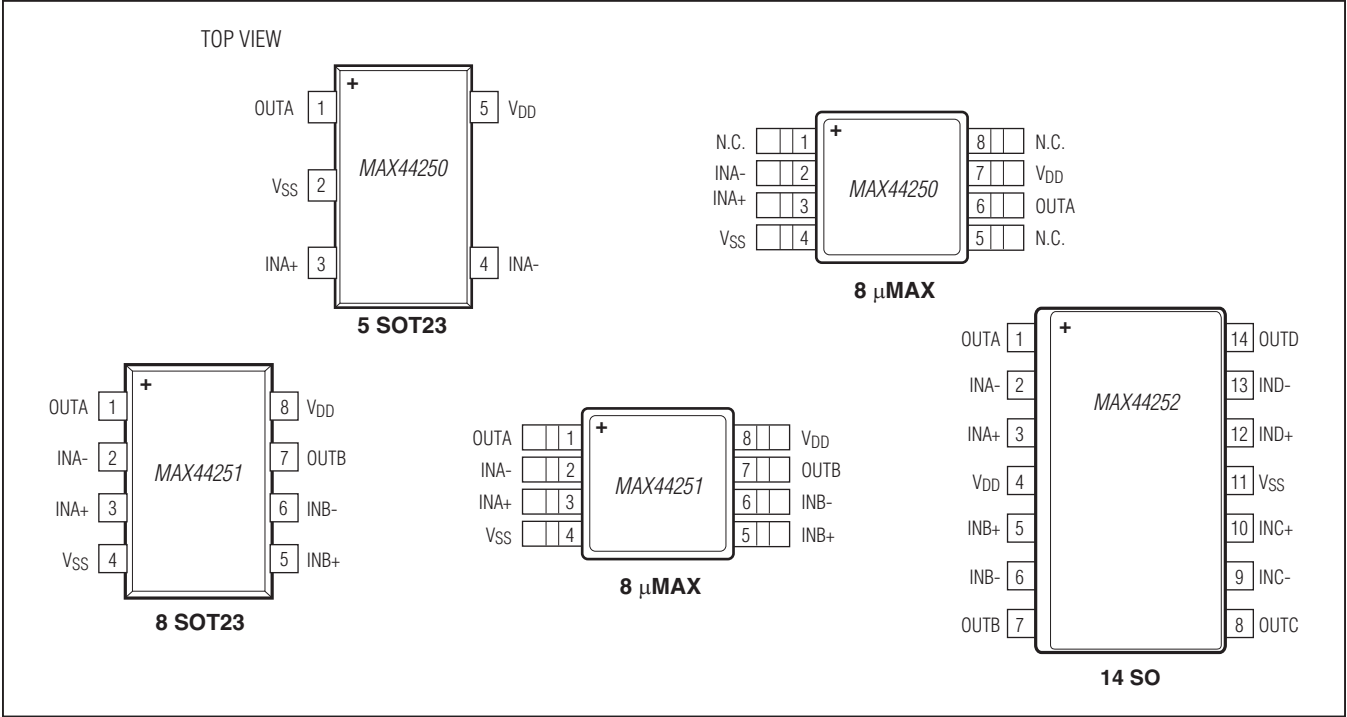
($V_{DD} = 10V$, $V_{SS} = 0V$, outputs have $R_L = 10k\Omega$ to $V_{DD}/2$. $T_A = +25^\circ C$, unless otherwise specified.)



MAX44250/MAX44251/
MAX44252

20V, Ultra-Precision, Low-Noise Op Amps

Pin Configurations



Pin Description

PIN					NAME	FUNCTION
MAX44250		MAX44251		MAX44252		
5 SOT23	8 μ MAX	8 SOT23	8 μ MAX	14 SO		
1	6	1	1	1	OUTA	Channel A Output
4	2	2	2	2	INA-	Channel A Negative Input
3	3	3	3	3	INA+	Channel A Positive Input
2	4	4	4	11	VSS	Negative Supply Voltage
—	—	5	5	5	INB+	Channel B Positive Input
—	—	6	6	6	INB-	Channel B Negative Input
—	—	7	7	7	OUTB	Channel B Output
5	7	8	8	4	VDD	Positive Supply Voltage
—	—	—	—	8	OUTC	Channel C Output
—	—	—	—	9	INC-	Channel C Negative Input
—	—	—	—	10	INC+	Channel C Positive Input
—	—	—	—	12	IND+	Channel D Positive Input
—	—	—	—	13	IND-	Channel D Negative Input
—	—	—	—	14	OUTD	Channel D Output
—	1, 5, 8	—	—	—	N.C.	No Connection

Detailed Description

The MAX44250/MAX44251/MAX44252 are high-precision amplifiers that have less than $3\mu\text{V}$ of typical input-referred offset and low flicker noise. These characteristics are achieved through an autozeroing technique that samples and finds repeating patterns of signal to cancel the input offset voltage and $1/f$ noise of the amplifier.

Autozero

The ICs feature an autozero circuit that allows the devices to achieve less than $6\mu\text{V}$ (max) of input offset voltage at room temperature and eliminate the $1/f$ noise.

Noise Suppression

Flicker noise, inherent in all active devices, is inversely proportional to frequency presented. Charges at the oxide-silicon interface that are trapped-and-released by MOSFET oxide occurs at low frequency more often. For this reason, flicker noise is also called $1/f$ noise.

Electromagnetic interference (EMI) noise occurs at higher frequency that results in malfunction or degradation of electrical equipment.

The ICs have an input EMI filter to avoid the output getting affected by radio frequency interference. The EMI filter composed of passive devices presents significant higher impedance to higher frequency.

High Supply Voltage Range

The ICs feature 1.15mA current consumption per channel and a voltage supply range from either 2.7V to 20V single supply or $\pm 1.35\text{V}$ to $\pm 10\text{V}$ split supply.

Applications Information

The ICs are ultra-high-precision operational amplifiers with a high supply voltage range designed for load cell, medical instrumentation and precision instrument applications.

These devices are also designed to interface with pressure transducers and are ideal for precision weight scale application as shown in [Figure 1](#).

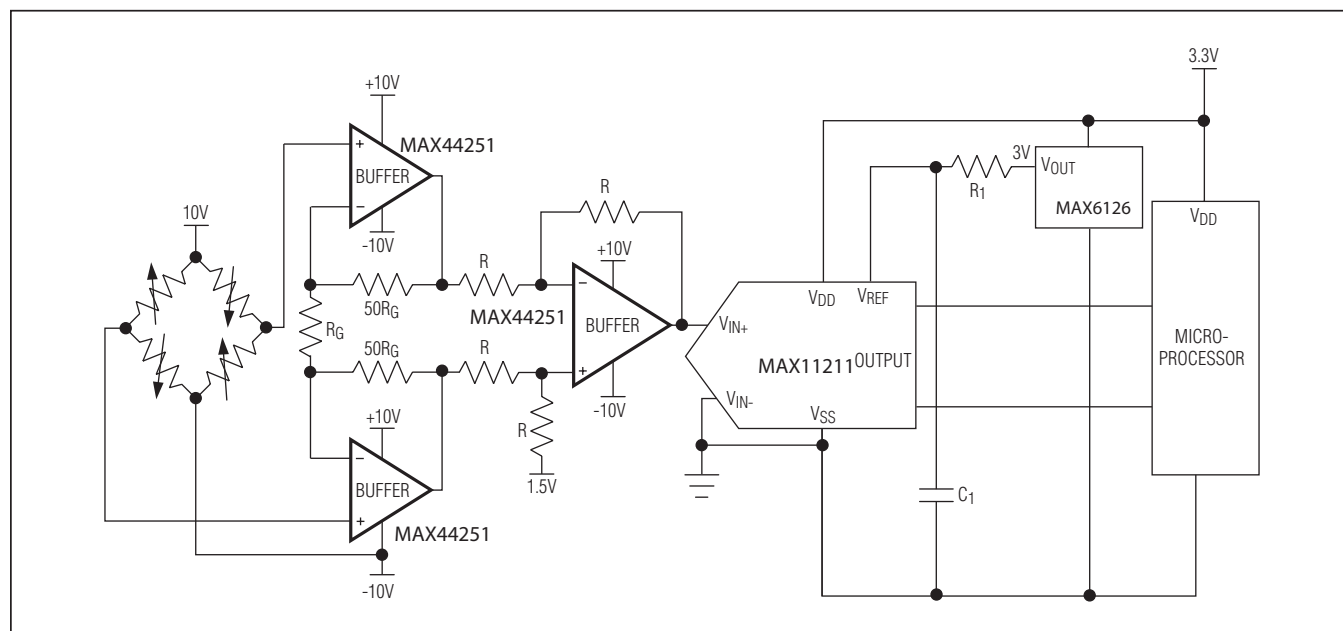


Figure 1. Weight Scale Application Circuit

ADC Buffer Amplifier

The MAX44250/MAX44251/MAX44252's low input offset voltage, low noise, and fast settling time make these amplifiers ideal for ADC buffers. Weigh scales are one application that often require a low-noise, high-voltage amplifier in front of an ADC. [Figure 1](#) details an example of a load cell and amplifier driven from the same $\pm 10\text{V}$ supplies, along with the MAX11211 18-bit delta sigma ADC. Load cells produce a very small voltage change at their outputs, therefore driving the excitation source with a higher voltage produces a wider dynamic range that can be measured at the ADC inputs.

The MAX11211 ADC operates from a single 2.7V to 3.6V analog supply, offers 18-bit noise-free resolution and 0.86mW power dissipation. The MAX11211 also offers > 100dB rejection at 50Hz and 60Hz. This ADC is part of a family of 16-, 18-, 20-, and 24-bit delta sigma ADCs with high precision and < 1mW power dissipation.

The MAX44250/MAX44251/MAX44252's low input offset voltage and low noise allow a gain circuit prior to the MAX11211 without losing any dynamic range at the ADC.

Error Budget Example

When using the ICs as an ADC buffer in strain gauge application, the temperature drift should be taken into consideration to determine maximum input signal. A typical strain gauge has sensitivity specification of just 2mV/V at rated out load. This means that when the strain gauge load cell is powered with 10V, the full-scale output voltage is 20mV. In this application, both offset voltage and drift are critical parameters that directly affect the accuracy of measurement. Even though offset voltage

could be calibrated out, its drift over temperature is still a problem.

The ICs, with a typical offset drift of 5nV/°C, guarantee that the drift over a 10°C range is only 50nV. Setting this equal to 0.5 LSB in a 18-bit system yields a full-scale range of 13mV. With a single 10V supply, an acceptable closed-loop gain of 770V/V provides sufficient gain while maintaining headroom.

Precision Low-Side Current Sensing

The ICs' autozero feature produces ultra-low offset voltage and drift, making them ideal for precision current-sensing applications. [Figure 2](#) shows the ICs in a low-side current-sense configuration. This circuit produces an accurate output voltage, V_{OUT} equal to $I_{LOAD} \times R_{SENSE} \times (1 + R_2/R_1)$.

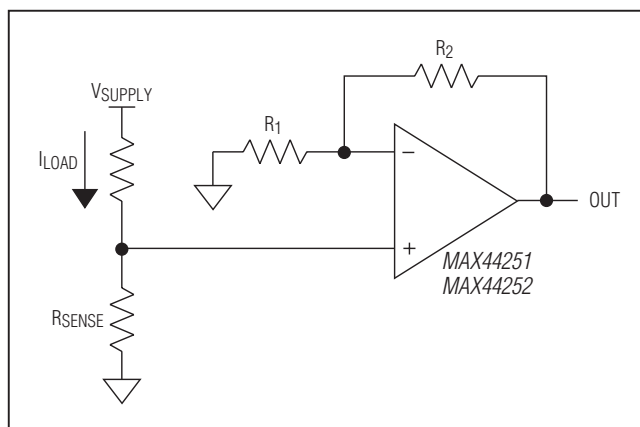
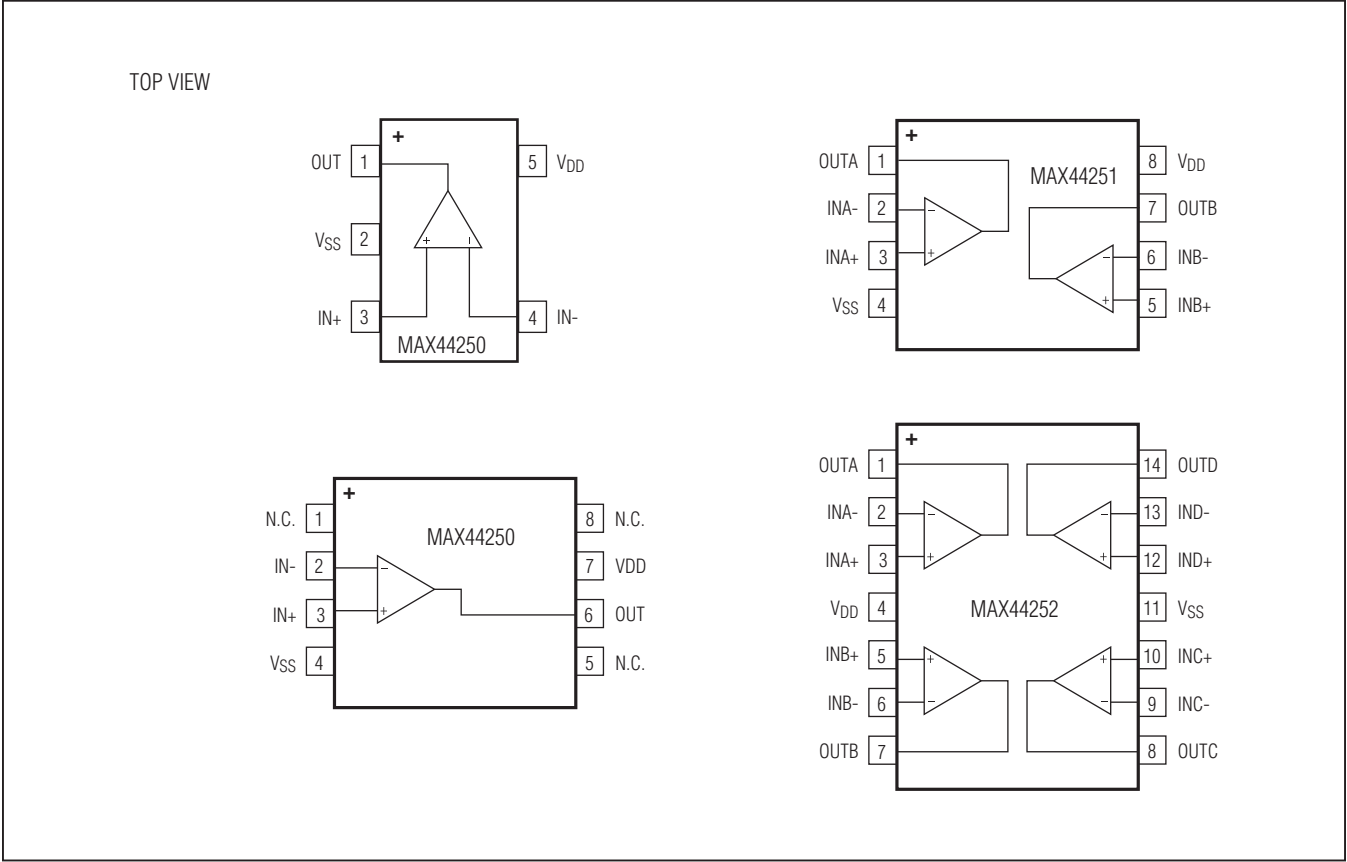


Figure 2. Low-Side Current Sensing

MAX44250/MAX44251/
MAX44252

20V, Ultra-Precision, Low-Noise Op Amps

Functional Diagrams



Chip Information

PROCESS: BiCMOS

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	TOP MARK
MAX44250AUK+	-40°C to +125°C	5 SOT23	AFMA
MAX44250AUA+	-40°C to +125°C	8 μMAX	—
MAX44251AKA+	-40°C to +125°C	8 SOT23	AERC
MAX44251AUA+	-40°C to +125°C	8 μMAX	—
MAX44252ASD+	-40°C to +125°C	14 SO	—

+Denotes a lead(Pb)-free/RoHS-compliant package.

Package Information

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
5 SOT23	U5+1	21-0057	90-0174
8 SOT23	K8+5	21-0078	90-0176
8 μ MAX	U8+1	21-0036	90-0092
14 SO	S14M+5	21-0041	90-0112

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	10/11	Initial release	—
1	12/11	Released the MAX44252 and updated the <i>Typical Operating Characteristics</i>	5, 6, 11
2	8/12	Added the MAX44250 to the data sheet, added MAX44251 EMIRR graph to <i>Typical Operating Characteristics</i> , and revised Figure 2	1–16
3	4/13	Updated <i>General Description</i> , <i>Typical Operating Circuit</i> , and Figure 1	1, 10
4	6/14	Corrected <i>Package Information</i>	13
5	5/15	Added the <i>Benefits and Features</i> section	1
6	1/17	Updated Functional Diagram to fix error	12

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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